

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

FCPF190N60E



- With TO-220F packaging
- High speed switching
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• ABSOLUTE MAXIMUM RATINGS(T_a=25℃)

APPLICATIONS

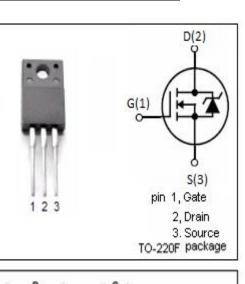
- Power supply
- DC-DC converters
- Motor control
- Switching applications

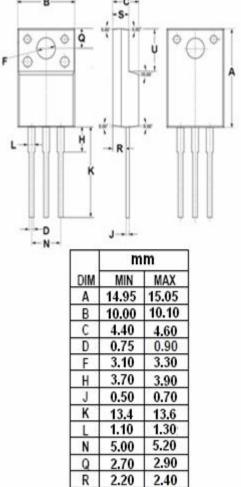
ABSOLUTE MAXIMUM RATINGS(Ta-23 C)							
SYMBOL	PARAMETER		VALUE	UNIT			
V _{DSS}	Drain-Source Voltage		600	V			
V _{GSS}	Gate-Source Voltage		±20	V			
ID	Drain Current-Continuous	Tc=25℃ Tc=100℃	20.6 13.1	A			
I _{DM}	Drain Current-Single Pulsed		61.8	А			
PD	Total Dissipation		39	W			
Tj	Operating Junction Temperature		-55~150	°C			
T _{stg}	Storage Temperature		-55~150	°C			

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	3.2	°C /W	
Rth(ch-a)	n-a) Channel-to-ambient thermal resistance		°C/W	

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2.65

6.40

S

U

2.90

6.60

isc website: www.iscsemi.cn



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ELECTRICAL CHARACTERISTICS

$T_{C}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =10mA	600			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =±20V; I _D =0.25mA	1.0		3.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =10A		0.16	0.19	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 480V; V _{GS} = 0V;Tj=25℃ Tj=125℃			1 10	μA
V _{SDF}	Diode forward voltage	I _{SD} =10A, V _{GS} = 0 V			1.2	V

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